HALOGEN

FREE



Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 5.0 \text{ A}$



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _{RRM}	45 V				
I _{FSM}	160 A				
V _F at I _F = 10 A	0.41 V				
T _{OP} max. (AC mode)	150 °C				
T _J max. (DC forward current)	200 °C				
Package	TO-220AB				
Diode variation	Dual Common Cathode				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

· High efficiency operation

• Solder dip 275 °C max. 10 s, per JESD 22-B106

• T_{.I} 200 °C max. in solar bypass mode application

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT2045CBP	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)} ⁽¹⁾	20	А	
	per diode		10		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	160	А	
Operating junction and storage temperature range (AC mode)		T _{OP} , T _{STG}	-40 to +150	°C	
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$		T _J ⁽²⁾	≤ 200	°C	

Notes

- (1) With heatsink
- (2) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V	
	I _F = 10 A			0.49	0.58		
	I _F = 5 A	T _A = 125 °C		0.33	-		
	I _F = 10 A			0.41	0.52		
Reverse current per diode	V _D = //5 V	T _A = 25 °C	I _R ⁽²⁾	-	2000	μΑ	
		T _A = 125 °C		10	30	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VT2045CBP	UNIT		
Typical thermal resistance	per diode	R _{θJC}	3.0	°C/W	
	per device		2.0		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	VT2045CBP-M3/4W	1.88	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

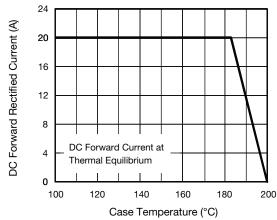


Fig. 1 - Maximum Forward Current Derating Curve

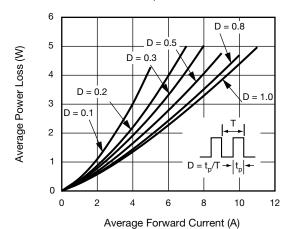


Fig. 2 - Forward Power Loss Characteristics Per Diode



100

10

0.1

0.01

0.001

Instantaneous Reverse Current (mA)

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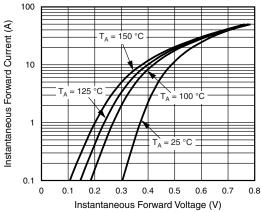
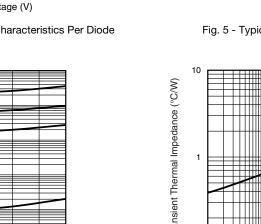


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

Γ_Λ = 150 °C

T_A = 25 °C

= 125 °C



Percent of Rated Peak Reverse Voltage (%)
Fig. 4 - Typical Reverse Characteristics Per Diode

60

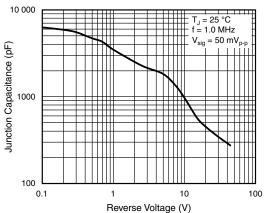


Fig. 5 - Typical Junction Capacitance Per Diode

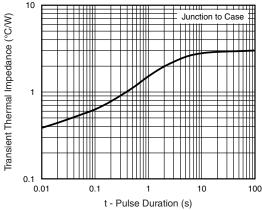


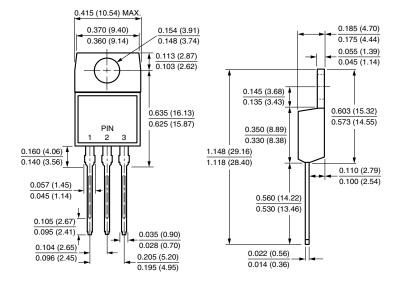
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

80

100

TO-220AB





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